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TERAHERTZ FREE-ELECTRON LASER OPTICAL DESIGN
AND SIMULATIONbyAaron ZimmerJune 2010Thesis Advisor:Second Reader:K. L. Armstead

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TERAHERTZ FREE-ELECTRON LASER OPTICAL DESIGN AND SIMULATION

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ABSTRACT

The Free Electron Laser (FEL) provides a versatile method for producing laser light. Traditionally, FELs are complicated in design and occupy large research facilities. The primary goal of this thesis is to investigate a particular FEL design that is small in size and operates in the terahertz (THz) frequency regime. The optics materials requirements are explored for power levels ranging from milliwatts to kilowatts. Additionally, as part of а simpler design and in spite of the large amount of diffraction present at THz wavelengths, a waveguide will not be utilized as others have done previously. Laser beam clipping, which is defined as the absorption of the laser beam at the outer edges of the diffracted mode, and a shortened undulator, are investigated as methods to support the elimination of the waveguide.

TABLE OF CONTENTS

I.	INTRODUCTION
II.	<pre>"PARTS LIST" FOR A RECIRCULATING FREE ELECTRON LASER. 5 A. ELECTRON BEAM</pre>
111.	FEL THEORY9A.RESONANCE CONDITION AND PENDULUM EQUATION10B.WAVE EQUATION12
IV.	OPTICAL THEORY / ATMSOPHERIC PROPAGATION17A. DIFFRACTION17B. ABSORPTION19C. THERMAL BLOOMING21D. TURBULENCE23
v.	OPTICS25A. MATERIAL CONSIDERATIONS251. Single Crystal Sapphire262. Crystal Quartz273. Silicon274. Zinc Selenide (ZnSe)295. Chemical Vapor Deposition Diamond30B. HEAT TRANSFER OUT OF A LENS / WINDOW32C. LINEAR EXPANSION OF OPTICAL MATERIALS35D. MAXIMUM ALLOWABLE POWER36E. COMBINED CRITERIA37
VI.	DESIGN PROPOSALS
VII.	CLIPPING SIMULATION RESULTS

	Α.	WEAK FIELD GAIN	46
	в.	STRONG FIELD EXTRACTION	49
VIII.	CONCL	USION	53
LIST OF	' REFE	RENCES	55
INITIAL	DIST	RIBUTION LIST	5 9

LIST OF FIGURES

Figure	1.	Major parts of a recirculating Free Electron Laser. Electron beam is shown in red, the
		optical beam is shown in purple and blue. The
		undulator, shown in green, is where energy is
		transferred from the electron beam to the
		optical beam. From [3]5
Figure	2.	Major parts of an undulator as used in a FEL.
		After [4]
Figure	3.	FEL electron-photon interaction. From [1]9
Figure	4.	Optical diffraction of a FEL. After [5]18
Figure	5.	Transparency of atmosphere at sea level. From
		[7]
Figure	б.	Thermal blooming of a continuous wave beam through stationary atmosphere, where T is
		temperature of the air 0 is the mass density
		of the sir and n is the index of refraction
		Erom [2]
Figuro	7	Optical transmission of a 1 mm thick sample of
FIGULE	1.	Single Crystal Sapphire us wavelength From
		[10] Single Crystal Sapphile VS. wavelength. Flom
Figuro	0	(IU)
rigure	ο.	Crustal Quarte us wavelength From [12]
Figuro	0	Optical transmission of a 5 mm thick sample of
rigure	9.	UDEZ Giligon ug wavelength Erem [12]
E ' aumo	10	Optical transmission anastrum of silison us
rigure	10.	temperature [11]
Figuro	1 1	Optical transmission of a 10 mm sample of ZnCo
rigure	11.	up up the statistic of a to the sample of side
E ' aumo	10	Optical transmission apostrum of a 1 mm thick
Figure	12.	optical transmission spectrum of a 1 mm thick
E ' aumo	1 2	Sample of CVD Diamond VS. wavelength [16]
Figure	13.	heat transfer estimation for a thin fens. From
		If the fight in the state view.
	1 /	Alter [18]
Figure	14.	weak optical field gain vs. optical beam
		clipping
Figure	15.	Optimal electron phase velocity v_0 vs. optical
		beam clipping for weak fields 48
Figure	16.	Strong optical field extraction η vs. optical
		beam clipping 49
Figure	17.	Optimal electron phase velocity v_0 vs. optical
		beam clipping for strong fields 50

LIST OF TABLES

Table 1	L.	Various ww ₀	for diff	erent w	vavelength	ls	20
Table 2	2.	Comparison o	of all op	tical ma	aterials	considered	. 32
Table 3	3.	Desired ene	ergies	to atta	ain wave	lengths o	of
		interest	••••				43

LIST OF ACRONYMS AND ABBREVIATIONS

ARPA	Advanced Research Projects Agency				
dB	Decibel				
ERL	Energy Recovery Linear Accelerator				
FEL	Free Electron Laser				
HF	Hydrogen Fluoride				
HRFZ	High Resistivity Float Zone				
ICBM	Inter-Continental Ballistic Missile				
K	Kelvin				
KE	Kinetic Energy				
Km	Kilometer				
LASER	Light Amplification by Stimulated Emission of Radiation				
MeV	Mega Electron Volt				
MIRACL	Mid-Infrared Advanced Chemical Laser				
RF	Radio Frequency				
THz	Terahertz				
ZnSe	Zinc Selenide				

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xv

I. INTRODUCTION

The Free Electron Laser (FEL) is one of many types of lasers currently in use around the world. It operates on the principle that stimulated emission occurs when an electron is accelerated in the presence of light. Unlike other types of lasers, the FEL is tunable over a wide range of optical wavelengths, which provides an enormous number of possible future uses. In this paper, the use of FELs in the Terahertz (THz) regime is examined, specifically in the range from 100-300 microns and from 10-30 microns, where each range presents its own specific challenges. The absorption, transmission, and reflection of light in these ranges are wholly dependent on the materials used for the optical components in the laser system and on the medium in which the beam is transmitted. Both of these areas are considered further in this thesis.

A. HISTORY

The recent history of lasers dates back to 1960, with the creation of the first LASER by Theodore Maiman at the Hughes Research Laboratory in California.

This small, pulsed laser was a surprise to many in the field who had not considered a pulsed laser beam. However, very shortly after this first pulsed laser's introduction to the world, a second ruby laser, which was well funded by ARPA (the Advanced Research Projects Agency), was made by Ron Martin at TRW [1].

The ruby laser showed its viability up to a power as high as 30 watts; by about 1965, however, it had become

apparent that above that energy level, the ruby laser displayed heat dissipation problems, with the laser rods shattering from the heat.

Around this same time, high-power gas lasers were being considered, with the expectation that troublesome heat could be more easily removed than in a ruby laser. In mid-1965, C. Kumar N. Patel produced a 200-watt 10 μ m continuous wave carbon dioxide laser at Bell Laboratories. Later, Hughes reached 1.5 kW with a gas laser which, however, had an extremely low efficiency of ~ 0.1%. Gas lasers continued to make progress and, in 1979, the Air Force put a 400 kW gas-dynamic laser in a Boeing 707-and 2 years later it was able to shoot down an air-to-air missile.

In the 1970s and 80s, the U.S. Navy became interested in chemical lasers, which have a wavelength of $\sim 3-4$ µm. In 1978, the 400 kW Navy ARPA chemical laser became the first chemical laser to shoot down a missile in flight. In 1980, TRW completed the first megawatt-class laser, the MIRACL (Mid-Infrared Advanced Chemical Laser). It could emit a 2 MW beam, but only for a few seconds at a time, and thermal blooming was a major issue with beam propagation. Additionally, the laser itself was huge, not portable in any sense.

Enter the Star Wars Era, when lasers received renewed attention for their expected ability to reach into space and knock down ICBMs. In 1991, a 2.7 μ m HF laser named Alpha finally reached the megawatt class. Then, after

having poured money into laser research with little or no results, United States funding all but disappeared after the fall of the Soviet Union.

The 1990s saw few new laser weapons under development. These were mostly for use in defense against short-range rockets and mortars. Chemical lasers are somewhat effective, but they are too bulky, so current research is refinements of re-examining the original solid-state lasers. Solid-state lasers have now been produced at powers up to 100kW and may be a viable option in the future.

One of the more recent additions to the arena is the FEL. John Madey, of Stanford University, first proposed the FEL in 1970 and subsequently demonstrated one in 1976. Current research has led to a 14 kW FEL at Jefferson Laboratory, and a contract was awarded recently by the Office of Naval Research (ONR) to Raytheon and Boeing to develop the preliminary design of a 100 kW experimental FEL for the U.S. Navy [1].

Currently, there are many FELs in operation around the world, as can be seen in the "Free Electron Lasers in 2008" paper, produced by the Naval Postgraduate School with support from ONR [2]. Experiments probing uses as varied as unobtrusive cargo scanning at shipping ports to wireless power transport into space currently are being considered.

II. "PARTS LIST" FOR A RECIRCULATING FREE ELECTRON LASER

The Free Electron Laser (FEL) is made up of several components that all work together to create a useable light beam. There are two important players in the FEL: the first is the electron beam and the second is the optical beam. Both are depicted in Figure 1.



Figure 1. Major parts of a recirculating Free Electron Laser. Electron beam is shown in red, the optical beam is shown in purple and blue. The undulator, shown in green, is where energy is transferred from the electron beam to the optical beam. From [3].

A. ELECTRON BEAM

The electron beam components include the injector, accelerator, beam transport system, undulator, and beam dump.

1. Electron Injector

Free electrons originate in the injector, provided by thermal emission or photo-emission from the cathode surface. They are then accelerated away from the cathode and into the injector via a static or RF electric field.

2. Electron Accelerator

Following the initial injection of the electron beam, it goes through a linear electron accelerator. The electron accelerator uses alternating, intense electric fields, stored in radiofrequency (RF) cavities, to accelerate the charged electrons, increasing their energy. As the electrons leave one cavity, they are synchronized so that they see only continual acceleration. Electrons come out of different accelerators with energies ranging from a few MeV to thousands of MeV.

3. Electron Beam Transport

After the accelerator, bending magnets, placed as needed along the red beam line of Figure 1, redirect the electron beam to the undulator. Surrounding the undulator is the oscillator, consisting of a highly reflecting mirror, and an out-coupling mirror. The electron beam is in a nearly perfect vacuum inside a beam pipe.

4. Undulator

This redirected beam then continues on to the oscillator and travels through the undulator. The undulator uses a series of alternating magnetic fields, as seen in Figure 2, to wiggle the electrons back and forth

slightly in the transverse direction as they pass through, emitting electromagnetic radiation in the form of light as a consequence.



Figure 2. Major parts of an undulator as used in a FEL. After [4].

This emitted light becomes the basis for the Free Electron Laser "light" beam, as it oscillates back and forth between the reflecting and out-coupling mirrors, which make up the resonator. The out-coupling mirror is partially transmitting and lets a small portion of the light go through the mirror. This exiting light is the portion of the light beam that becomes the "pointy edge of the spear" of the FEL.

5. Beam Recovery and Dump

An additional feature of an Energy Recovery Linear Accelerator (ERL)-type FEL is that there is a low energy beam dump after energy is recovered in the decelerating section. After the electron beam passes through the oscillator, it continues through bending magnets back to the electron accelerator, where most of the beam's energy is recovered by sending the electrons through the accelerator cavity 180 degrees out of phase. As the beam slows, this recovered energy is transferred to the intense electric fields within the accelerator and then transferred to the beam now leaving the injector and beginning its positive acceleration.

Any energy left in the waste electron beam is then sent to the beam dump, usually a large piece of copper.

B. OPTICAL BEAM

The optical beam components include the optical beam cavity and optical beam piping to subsequent applications.

1. Optical Cavity

The optical cavity consists of two mirrors placed at the ends of the undulator and maintained in a near perfect vacuum. One mirror is 100% reflecting while the other transmits a small amount of light. The distance between the mirrors is critical and must be constantly maintained to ensure that successive light pulses are kept in phase with the electron pulses while transiting through the undulator. These mirrors must also maintain proper alignment at all times.

2. Optical Beam Piping and Transport

The optical beam is transported and directed via a series of mirrors and lenses.

III.FEL THEORY

A laser is a mechanism for emitting electromagnetic radiation through a process called stimulated emission. A Free Electron Laser can generate coherent, high power radiation, over a large frequency spectrum. This ability to operate over a wide wavelength range is unique among all lasers and allows the FEL to be used for many purposes.

While the FEL consists of many important components, the undulator, illustrated in Figure 3, is its essential distinguishing feature and is where the electron-photon interaction takes place.



Figure 3. FEL electron-photon interaction. From [1].

The green line shows one period, $\lambda_{
m o}$, of the undulator; the blue wave indicates one wavelength, λ , of the optical wave, and the red dot shows the position of the electron relative to the optical wavelength. The electron (red dot) and the optical wave (blue wave) are shown at five intervals as they both pass through the period of the undulator. Inside the optical cavity of the FEL resonator, the electron bunches wiggle through the undulator and emit light. Since electrons cannot travel at the speed of light, the light wave moves forward with respect to the This is referred to as the *electron-photon* electrons. Resonance occurs when the light advances by one race.

optical wavelength relative to the electron, for each oscillation of the electron in the undulator field. This resonance condition, and the theory of operation for a FEL, is described below.

A. RESONANCE CONDITION AND PENDULUM EQUATION

The electron motion in an FEL is determined by the relativistic force equations (cgs units):

$$\frac{d(\gamma\beta)}{dt} = -\frac{e}{mc}(\vec{E} + \vec{\beta} \times \vec{B}) , \qquad (\texttt{II.1})$$

$$\frac{d\gamma}{dt} = -\frac{e}{mc}\vec{\beta}\cdot\vec{E} , \qquad (\text{II.2})$$

$$\gamma^{-2} = 1 - \vec{\beta}^2 , \qquad (\texttt{II.3})$$

where $\vec{v} = \vec{\beta}c$ is the electron velocity, m is the electron mass, and e is the electron charge magnitude, γ is the relativistic Lorenz factor, \vec{E} and \vec{B} are the electric and magnetic fields, respectively.

When an electron enters the undulator of an operating FEL, the undulator and optical fields together determine its motion. Substituting the laser and undulator fields into the Lorenz force equations and realizing that for relativistic electrons $\beta_z \approx 1$ and that the transverse motion in the undulator is determined by $\vec{\beta}_{\perp} = -\frac{K}{\gamma}(\cos k_0 z, \sin k_0 z, 0)$, where $k_0 = 2\pi/\lambda_0$ and K is the dimensionless undulator parameter, we arrive at an electron's equation of motion given by

$$\dot{\gamma} = \frac{d\gamma}{dt} = -\frac{e}{mc} E[\beta_x \cos\psi - \beta_y \sin\psi] = \frac{eKE}{\gamma mc} \cos(\zeta + \phi) , \qquad (\text{II.4})$$

where $\psi = kz - \omega t + \phi$, E is the optical electric field amplitude in cgs units, ϕ is the optical phase, $k = 2\pi/\lambda$ is the wavenumber, λ is the wavelength, ω is the frequency, and $\zeta = (k + k_0)z - \omega t$ is the electron phase (which is used to measure the electron position on the scale of the optical wavelength (~1µm)).

At this point, it is useful to define the "electron phase velocity" as

$$v = \dot{\zeta}L / c = L[(k + k_0)\beta_z - k] = \dot{\zeta} , \qquad (II.5)$$

where () indicates a derivative with respect to dimensionless time $\tau = ct/L$ so that τ goes from 0 to 1 along the undulator length, L, i.e., as τ goes from 0 to L/c.

In a beam of electrons, each electron has a different initial phase $\zeta(0) = \zeta_0 = (k + k_0)z_0 \approx kz_0$ as it begins its path through the undulator. The electron's energy changes as seen in Equation (II.4) affect the microscopic position through the electron phase ζ and phase velocity v. Now consider $\dot{v} = L[(k + k_0)\dot{\beta}_z]$ where $\beta \approx 1 - (1 + K^2)/2\gamma^2$ in the relativistic limit $(\gamma \gg 1)$. Using this $\dot{\beta}_z$ in the relativistic limit and near resonance (the condition where optimum energy transfer occurs between the electron beam and optical field), we find $\dot{v} = 4\pi N \dot{\gamma}/\gamma$, where N is the number of undulator periods.

This leads to the final dimensionless FEL pendulum equation

$$\overset{\circ}{V} = \overset{\circ}{\zeta} = |a|\cos(\zeta + \phi), \qquad (\text{II.6})$$

where $|a| = 4\pi NeKLE / \gamma^2 mc^2$ is the dimensionless optical field amplitude.

The pendulum equation (II.6) helps identify how in a typical FEL the electrons (~10⁶ of them), which are randomly spread over each wavelength in the beam, bunch and radiate coherently. About half of the electrons are moving slightly faster and half are moving slightly slower within each section of the electron beam about one laser wavelength long. A net energy transfer occurs if the electrons have a net change in their average velocities, i.e., the beam bunches at the correct phase, $\delta + \phi = \pi$.

B. WAVE EQUATION

The response of the laser field to the electrons is determined by the wave equation. Start with the full wave equation,

$$\left(\vec{\nabla}^2 - \frac{1}{c^2}\frac{\partial^2}{\partial t^2}\right)\vec{A}(\vec{x},t) = \frac{4\pi}{c}\vec{J}_{\perp}(\vec{x},t) , \qquad (\text{II.7})$$

where $\vec{A}(\vec{x},t)$ is the optical vector potential, \vec{J}_{\perp} is the current source, and c is the speed of light. The laser's electric and magnetic fields can be derived from the vector potential using

$$\vec{E} = -\frac{1}{c} \frac{\partial \vec{A}}{\partial t} , \qquad (II.8)$$

$$\vec{B} = \nabla \times \vec{A} , \qquad (\texttt{II.9})$$

Since the laser beam is coherent, $A(\vec{x},t)$ has a slowly varying envelope $E(\vec{x},t)$ in the direction of propagation along z, and the slowly-varying, complex optical vector potential can be written in the form

$$\vec{A}(\vec{x},t) = \frac{E(\vec{x},t)}{k} \hat{\varepsilon} e^{i\alpha} , \qquad (\texttt{II.10})$$

where $\alpha = k_z - \omega t$ represents the "carrier wave," $E = |E| e^{i\phi}$ is the complex laser electric field, and $\hat{\varepsilon}$ is the laser field's polarization vector.

Now the wave's amplitude and phase are taken to be slowly varying along the z axis and also slowly varying in time, the left side of the laser wave equation can be written as

$$\frac{\hat{\varepsilon}e^{i\alpha}}{k} \left[\vec{\nabla}_{\perp}^2 + 2ik \left(\frac{\partial}{\partial z} + \frac{1}{c} \frac{\partial}{\partial t} \right) \right] E = -\frac{4\pi}{c} \vec{J}_{\perp} . \qquad (\texttt{II.11})$$

After multiplying both sides of the equation by $ke^{-i\alpha}\hat{\varepsilon}^*$ and introducing a coordinate u=z-ct to use the "method of characteristics," the wave equation can be written as

$$\left[\vec{\nabla}_{\perp}^{2} + 2ik\left(\frac{1}{c}\frac{\partial}{\partial t}\right)\right]E = -\frac{4\pi k}{c}\vec{J}_{\perp}\cdot\hat{\varepsilon}^{*}e^{-i\alpha}. \qquad (\texttt{II.12})$$

Making substitutions for $ec{eta}_{ot}$ in $ec{J}_{ot}$ gives

$$\left[\vec{\nabla}_{\perp}^{2} + \frac{2ik}{c}\frac{\partial}{\partial t}\right]E = -4\pi i e K k \rho(\vec{x},t) < e^{-i\zeta} / \gamma >_{(\vec{x},t)}, \qquad (\texttt{II.13})$$

where $\rho(\vec{x},t)$ is the local electron density in a small volume dV located at position (\vec{x},t) and $\zeta = (k+k_0)z - \omega t$ is again the electron phase, and <> indicates the average value.

Now introduce dimensionless time $\tau = ct/L$ where L is the length of the undulator so that $\tau = 0 \rightarrow 1$ during the interaction along the undulator and multiply the wave equation by the factor $-4\pi NeKL^2/\gamma_0^2mc^2k$ so

$$\left[-\frac{iL}{2k}\vec{\nabla}_{\perp}^{2}+\frac{\partial}{\partial\tau}\right]a(\vec{x},\tau)=-\langle je^{-i\zeta}\rangle_{(\vec{x},\tau)}, \qquad (\text{II.14})$$

where the dimensionless laser field amplitude is again $|a| = 4\pi NeKL |E|/\gamma_0^2 mc^2$, the complex laser field is $|a| = e^{i\phi}$, the dimensionless FEL current density is $j = 8\pi^2 Ne^2 K^2 L^2 \rho / \gamma_0^3 mc^2$, and assuming that $\gamma \approx \gamma_0$ for all the electrons in the beam and during the entire interaction.

In order to write the wave equation more compactly, we define the dimensionless transverse coordinates $\tilde{x} = x(k/2L)^{1/2}$ and $\tilde{y} = y(k/2L)^{1/2}$, and now $\vec{\nabla}_{\perp}^2 = \partial_{\tilde{x}}^2 + \partial_{\tilde{y}}^2$, the fully dimensionless wave equation becomes

$$\left[-\frac{i}{4}\vec{\nabla}_{\perp}^{2} + \frac{\partial}{\partial\tau}\right]a(\vec{x},\tau) = -\left\langle je^{-i\zeta}\right\rangle_{(\vec{x},\tau)}, \qquad (\text{II.15})$$

When diffraction is small and the beams overlap exactly, the FEL wave equation can be written in its simplest form

$$a^{\circ} = -j < e^{-i\zeta} > ,$$
 (II.16)

The dimensionless current density j measures the coupling (and gain) between the laser light and electron beam, $\langle e^{-i\zeta} \rangle$ measures the average amount of bunching in the beam, and $\vec{\nabla}_{\perp}^2$ term in Equation (II.15) describes the possible diffraction of the beam. When the bunched electrons start to

remove energy from the optical beam, saturation has been achieved and the growth of the optical field ceases.

IV. OPTICAL THEORY / ATMSOPHERIC PROPAGATION

Now that the description of FEL Theory is complete, it is important to discuss how the laser light will interact in the atmosphere as it is transmitted. There are four major atmospheric effects as a laser beam is propagated through the atmosphere. These effects can lead to attenuation, broadening, defocusing, and deflection of the beam from its initial propagation path [2]. The four areas of most concern to THz FEL propagation in the atmosphere are diffraction and absorption and, in higher power applications, thermal blooming and turbulence.

A. DIFFRACTION

In the simplest terms, FEL beam diffraction can be described as the spreading of a Gaussian beam as it propagates. This spreading is caused by the physical property of electromagnetic waves to eventually spread as they propagate and can be easily affected by changing the size of the optical mode waist radius (w_0) .

The equation governing the diffraction of an optical Gaussian beam is

$$w(z) = w_0 \left(1 + \frac{z^2}{z_R^2}\right)^{\frac{1}{2}}$$
 (IV.1)

where w(z) is the coherent optical mode radius at distance z, w_0 is the optical mode waist, and z_R is the Rayleigh length. The Rayleigh length is determined from

$$z_R = \frac{\pi w_0^2}{\lambda} \tag{IV.2}$$

where λ is the optical wavelength of the beam. Figure 4 provides a physical representation of how a Gaussian beam spreads with distance.



Figure 4. Optical diffraction of a FEL. After [5].

If the approximation is made that the propagation distance z is much greater than the Rayleigh length z_R , then

$$ww_0 \simeq \frac{z\lambda}{\pi} \tag{IV.3}$$

and from Equation (IV.3) it is easy to determine that if you hold z and λ constant, then w and w_0 can be adjusted as needed to satisfy the equation. This ability to manipulate w and w_0 in order to satisfy the diffraction Equation (IV.1) is important for applications where w at distance z is specified so that w_0 determines the aperture size.
B. ABSORPTION

Beer's law best describes absorption of laser beam in the atmosphere

$$\tau = \frac{I(z)}{I_0} = e^{-\alpha z} \qquad (IV.4)$$

where τ is the transmittance for a distance z, I is the irradiance at z, I₀ is the initial irradiance, and α is the absorption coefficient [2]. It is apparent from Equation (IV.4) that absorption is a process in which energy is removed via interaction with particles that are present in the atmosphere or other medium in which a beam is propagating. The absorption coefficient is dependent on the frequency of the light being transmitted and the size, number density, and type of the particles present in the transmission path.

A common way to describe atmospheric transmission in the atmosphere is as a loss in decibels (dB) per unit distance. When doing so, "the absorption of light during wave propagation is often called attenuation" [6].

Figure 5 describes the transparency of the atmosphere at sea level for various wavelengths. It is apparent that in the range from 300 to 30 μ m there is a significant amount of attenuation therefore making FEL operation in the regime impossible at long distances. As you approach 10 μ m, attenuation is much less significant and long-range laser propagation is possible. Note that weather effects can have a large effect on the propagation distance of a laser beam in the atmosphere.



Figure 5. Transparency of atmosphere at sea level. From [7].

When considering what distances can be propagated at in the THz regime, four different wavelengths were explored for this thesis. Pulling the approximate values for 50% atmospheric attenuation (3 dB/km loss) from the red curve on Figure 5 and applying Equation IV.3 for those four wavelengths provides the results displayed in Table 1.

Wavelength (µm)	z (3 dB Range)	ww ₀ (m²)	If $w_0 = 10$ cm, then
300	10 m	0.001	w ~ 10 cm
100	30 m	0.001	w ~ 10 cm
30	100 m	0.001	w ~ 10 cm
10	3 km	0.01	w ~ 100 cm

Table 1. Various ww_0 for different wavelengths

As can be seen from Table 1, as the wavelength is increased from 10 μ m to 300 μ m, the range achieved before a 3 dB loss occurs increases. In addition, the spot size and/or the optical mode waist (w and w₀) can be adjusted to attain the required value for the application consistent with the value of ww_0 . In this scenario, one can either fix the antenna size while varying the size of the beam at the target, or one can maintain a consistent beam size at the target and vary the antenna size. This decision will be made with respect to the application being considered.

C. THERMAL BLOOMING

As the optical power transmitted through the atmosphere reaches the kilowatt level, an atmospheric effect called thermal blooming can become а concern. Thermal blooming is the result of the nonlinear interaction of the FEL's optical beam and the absorption of the beam energy by the atmosphere, thereby heating the air and causing localized density gradients in the medium. These gradients result in the spreading of the laser beam, which spreads the beam and reduces the optical intensity at the An illustration of the effect of thermal target [8]. blooming is provided in Figure 6.



Figure 6. Thermal blooming of a continuous wave beam through stationary atmosphere, where T is temperature of the air, ρ is the mass density of the air, and n is the index of refraction. From [2].

There are a few factors that determine the thermal blooming effect on a laser beam. These include:

- 1. Laser beam characteristics, specifically the area
- 2. The propagation medium
- 3. The dwell time of the laser beam

These factors can to some degree be manipulated to minimize the occurrence of stagnation zones. These zones lead to heating of the stationary air in the center of the beam to higher temperatures than the air at the edges of the beam, which is the cause of the thermal blooming lens [2].

The effects of thermal blooming are of concern only over long distances in an absorptive medium such as the There are several methods that can be used to atmosphere. minimize thermal blooming: The first method is to simply reduce the intensity of the beam, which reduces the heating of the atmosphere and the resulting defocusing. However, this may not work in higher power applications. A second method is to increase the area of the beam, which may work in some cases but not others, such as ship self defense. And a third is to increase the cross movement of the medium in which the beam is propagating, so that the beam slews laterally across the atmosphere, which avoids the blooming With luck there will be a crosswind or the laser effect. platform may move to create its own crosswind, i.e., move perpendicular to the target line of sight.

D. TURBULENCE

Turbulence is driven by naturally occurring temperature variations in the atmosphere. As an optical beam transmits through the atmosphere, these temperature variations cause the beam to wander or spread and break up the beam's wave front into smaller, random incoherent beamlets. For many applications, such as ship selfdefense, it is important that the optical beam propagate very precisely and predictably at long distances. Adaptive optics can minimize the effects of turbulence while maintaining a highly concentrated, high power optical beam. Adaptive optics is an established method of reducing the effect of turbulence. One method of adaptive optics, currently in use on the U.S. Air Force Airborne Laser (ABL), is a system made of deformable mirrors that compensate for atmospheric turbulence as is occurs [9].

V. OPTICS

A. MATERIAL CONSIDERATIONS

Optical component materials are clearly important in any FEL design, and especially in the THz regime, due to the high levels of absorption of THz radiation that occurs in many common optics materials. As noted before in this thesis, the wavelength range considered to represent the THz regime is broadly defined as 10 to 300 μ m, or 1 to 30 THz.

For the transmission and propagation of these wavelengths there are unique challenges that must be overcome with respect to optical components. The preferred optical material will:

- Transmit a large fraction of the radiation entering the lens or window.
- Remove the heat absorbed in the lens at a rate equal to its entry into the lens.
- Expand a minimal amount as it is heated so that lens distortions are kept within reasonable limits.

In order to achieve these goals, several materials are examined and the results are displayed.

The materials considered for THz applications are Single Crystal Sapphire, Crystal Quartz, Silicon, Zinc Selenide, and CVD (Chemical Vapor Deposition) Diamond. Each of these is considered with respect to its thermal conductivity, coefficient of thermal expansion, and transmission of THz frequency radiation.

1. Single Crystal Sapphire

As can be seen from Figure 7, Single Crystal Sapphire has been shown to have good transmission properties at wavelengths from 0.3 μ m up to approximately 6 μ m [10]. Several other sources of information were explored, but transmission at wavelengths beyond 6 μ m was not found. The implication is that the transmission is very poor beyond this wavelength. Due to a lack of data available to determine Sapphires ability to transmit in the area of interest (10 to 300 μ m), Sapphire will not be considered further as a possible THz optics material with respect to its thermal conductivity or thermal expansion coefficient [10, 11].



Figure 7. Optical transmission of a 1 mm thick sample of Single Crystal Sapphire vs. wavelength. From [10].

2. Crystal Quartz

Optical transmission properties of crystal quartz were considered first and are displayed in Figure 8.



Figure 8. Optical transmission of a 1 mm thick sample of Crystal Quartz vs. wavelength. From [12].

As with Single Crystal Sapphire, there is a lack of available research to determine Crystal Quartz' ability to transmit in the THz regime. Therefore, do to the lack of encouraging data, Crystal Quartz will not be considered further as a possible THz optics material with respect to its thermal conductivity or thermal expansion coefficient.

3. Silicon

A specific type of silicon, called "High Resistivity Float Zone (HRFZ) Silicon," has a significant THz

transmission at wavelengths ranging from approximately 50 to 1000 μ m; greater than 50% of the radiation passes as can be seen in Figure 9 [13].



Figure 9. Optical transmission of a 5 mm thick sample of HRFZ Silicon vs. wavelength. From [13].

However, silicon is a poor thermal conductor (1.5 W/m°C) and is therefore limited to low power operation (only a few watts). Additionally, silicon's transmission of THz radiation is greatly reduced as temperatures increase above 25 degrees Celsius, as can be seen in Figure 10. This is an additional factor limiting this material to low power operation. Data concerning the affect of temperature on the other materials could not be found and is therefore not considered in this thesis.



Transmission Spectrum of Silicon (Si) at Several Temperatures (5.89mm thickness)

Figure 10. Optical transmission spectrum of silicon vs. temperature [11].

4. Zinc Selenide (ZnSe)

ZnSe turns out to be a very promising material but only for wavelengths below 20 µm; it does not transmit THz frequency radiation at wavelengths greater than 20 µm as can Figure 11. The relatively high thermal be seen in ZnSe (7.57×10^{-6}) and its poor expansion coefficient of thermal conductivity (18 W/m°C) already limits the material to low power usage (Watts). Transmission properties of ZnSe at wavelengths greater than 100 µm were not found. For low power operations where there is little or no heating, zinc selenide may be suitable [14].



Figure 11. Optical transmission of a 10 mm sample of ZnSe vs. wavelength [15].

5. Chemical Vapor Deposition Diamond

The real winner and obvious choice for THz optics is Chemical Vapor Deposition (CVD) Diamond. CVD Diamond has the highest thermal conductivity of any known natural substance at 3300 W/m°C. It has a very low thermal expansion coefficient on the order of 1×10^{-6} /°C, and it has a broad transmission range throughout the THz regime as is evidenced in Figure 12. Additionally, its transmission curve is relatively flat across the entire THz spectrum (10 to 300 µm) at ~ 70% [16, 17].



Figure 12. Optical transmission spectrum of a 1 mm thick sample of CVD Diamond vs. wavelength [16].

The only drawbacks to CVD Diamond are its relatively high price, the limited number of manufacturers that currently produce it as an optical grade component, and the lens thicknesses that can currently be produced (on the order of millimeters). For instance, a 2 mm thick, 5 cm diameter CVD diamond window can easily cost \$50,000.

A "stoplight" table, comparing the characteristics of each of the materials, is displayed in Table 2.

Material:	Thermal Conductivity:	Thermal Expansion Coefficient:	Transmission Range:
	(at 20 °C)	(x10 ⁻⁶ / °C)	(µm)
	(W/m°C)		
HRFZ Si	1.5	2.6	50 - 300
Quartz	1.3	0.59	< 3
Sapphire	42	5	< 6
Zinc Selenide	18	7.57	10 - 20
CVD Diamond	3300	1.2	10 - 300

Table 2. Comparison of all optical materials considered.

B. HEAT TRANSFER OUT OF A LENS / WINDOW

At power levels greater than a few Watts, there is a need to maintain the steady-state temperature of the optical components. The heat removal problem can be simplified and approximated as the radial flow of heat between two coaxial cylinders where a thin slice of these cylinders acts as the lens, as seen in Figure 13. The curvature of the lens is considered negligible here and no other heat loss mechanism is considered.



Figure 13. Heat transfer estimation for a thin lens. From left to right: front view and side view. After [18].

The beam is incident on the center of the lens (shown in white) as indicated by r_1 and the full radius of the lens is indicated by r_2 .

To determine the rate at which heat is removed from the lens, we start with the equation $\dot{Q} = -k_l 2\pi r l\Delta T / \Delta r$ for heat transfer between two coaxial cylinders [18], where \dot{Q} is the power conducted out of the lens (P_c) , k_l is the coefficient of heat transfer, l is the thickness of the lens, and ΔT is the temperature difference across the radius of the lens from r_1 to r_2 , and dr is the infinitesimal annular segment of radius. After integration, the heat removal process for a lens is governed by

$$P_c = \dot{Q} = \frac{\Delta T (2\pi l k_l)}{\ln \frac{r_2}{r_1}} \tag{V.1}$$

A CVD Diamond lens with the design characteristics below could sustain $P_c = \dot{Q} \approx 600$ watts of continuous heat removal. Taking into consideration that the coefficient of absorption of CVD Diamond is roughly 10% at ~ 10 µm wavelength [17], it is estimated that a \approx 6 kW optical beam could be designed and operated using CVD Diamond as a lens and window material.

Example: CVD Diamond Window Spot size radius $(r_1) = 1 \text{ cm}$ Radius of lens $(r_2) = 2.5 \text{ cm}$ Thickness of lens (l) = 5 mm $\Delta T \text{ from } r_1 \text{ to } r_2 = 5 ^{\circ}\text{C}$ $k_{\text{CVD Diamond}} = 33 \text{ W/cm}^{\circ}\text{C}$

From Equation (V.1), it is easy to see that there are several ways to improve the heat removal performance of the lens for a given material. Increasing the thickness of the lens will provide a linear increase in heat removal capability, but will prove troublesome with respect to the linear expansion and the absorption within the lens as it is heated. Another method would be to maintain a larger steady-state temperature difference across the radius of the lens. This would provide an increase in the heat removal capability of the lens, but could potentially also cause problems as the lens distortions become significant across the radius of the lens. A final method of increasing the heat transfer ability of a given lens material is to increase the size of the laser beam spot transmitting through the lens for a given lens radius. This is a possibility that may impact the performance of the laser by a minimal amount depending on the placement of the lens or window along the optical beam. Additionally, this method has a less significant impact on the heat removal performance of the lens because changing the radius of the spot is in Equation (V.1) as a logarithm and is therefore not a linear effect.

C. LINEAR EXPANSION OF OPTICAL MATERIALS

When considering different optical materials for use as optical lenses and windows in a FEL it is important to account for the axial expansion of a material to prevent interference with the transmission of the optical beam. Prevention of interference occurs by limiting the axial expansion of a material to less than the length of one optical wavelength. Several actions can be taken to limit the thermal expansion and thus the interference of a lens. The first would be to minimize the thickness of the lens, a second option is to limit the temperature difference across the surface of the lens as needed to minimize surface irregularities, and a third option is to choose a material with a low coefficient of expansion.

With respect to limiting the thickness of the lens or window, there is a limit at which the window will no longer be sufficiently strong to maintain the barrier between a high vacuum and atmosphere. Additionally, with respect to

a lens or a window, the thinner a material is, the less power can be removed from it steady state, thus limiting the power rating of the FEL.

The second option of limiting the temperature difference across the lens in order to prevent distortions would succeed in keeping the lens distortion free, but has a negative side effect of limiting the amount of heat that can be removed from the lens, limiting the total power of the FEL.

The third and least restricting option is to choose a material that has a very low coefficient of expansion, which is the approach taken in the material search conducted here.

D. MAXIMUM ALLOWABLE POWER

When will thermal expansion become a problem? Using CVD diamond again as an example, the wavelength of 10 µm with an allowable linear distortion of \sim 10% of the optical wavelength. Knowing that the coefficient of linear expansion for CVD Diamond is 1.2×10^{-6} /°C and again using a 5 thick lens, then mm the allowed expansion is $(10\%)(10\mu m)/5mm = 2x10^{-4}\%$. The temperature difference is quickly determined to be $2x10^{-4}\% / 1.2x10^{-6}\% / ^{\circ}C = 166^{\circ}C$, using $\Delta l/l = \alpha \Delta T$, where α is the coefficient of linear thermal expansion.

Now, Equation V.1 from Section B and taking into account this new ΔT we can determine the maximum amount of heat that can be continuously removed from the same CVD diamond optic. This new value is ~ 11 kW. This means that a CVD diamond optic with these specifications could transmit an optical beam of ~ 190 kW of power through it with less than 10% axial expansion. From this result one can conclude that it is possible to operate a THz FEL at powers of hundreds of kilowatts with much less than 1 optical wavelength of linear expansion. At 300 μ m, allowing for a 10% expansion would mean a calculated ΔT of ~ 5000°C, a temperature that no FEL optic will operate at, therefore linear expansion of the optic will not be the limiting factor in operational design.

E. COMBINED CRITERIA

Now consider combining our criteria into a single formula expressing the maximum power, P_0 , sustainable in a lens of thickness l, linear expansion coefficient α , absorption coefficient δ per unit thickness, and thermal conductivity k_l . The lens thickness expression is $\Delta l/l = \alpha \Delta T$ where ΔT is the temperature difference across the lens. Assume that we limit linear expansion to $\Delta l \approx 0.1 \lambda$ or less, so the maximum temperature difference can only be $\Delta T \approx 0.1 \lambda / l \alpha$ This temperature difference limits the power or less. conducted away to: $P_c = 2\pi l k_l \Delta T / \ln(2)$, assuming $r_2 = 2r_1$. In steady state operation, the power conducted out must equal the power absorbed, $P_{abs} = P_c$, and the power absorbed is estimated by $P_{abs} = P_0(1 - e^{-\delta l})$. So the single formula describing the limiting power incident on the lens before expanding by ~ $\lambda/10$ is estimated by

$$P_0 = \frac{\lambda k_l}{\alpha (1 - e^{-\delta l})} . \tag{V.2}$$

As an example, CVD diamond is limited to $P_0 \approx 40$ kW at 10 µm wavelength for a lens of l = 3 mm thickness. This is far above our requirements.

VI. DESIGN PROPOSALS

shown in Chapter IV, propagation through the As atmosphere at long wavelengths (>100 µm) is less successful Therefore, any long wavelength than at short wavelengths. design will be limited to propagation distances of tens of meters before half the power is attenuated. As the wavelengths shorten and approach 10 μ m, transmission ranges the order of kilometers are possible, on making it practical to consider power levels on the order of kilowatts.

As part of the desire to keep the THz FEL design simple, a number of steps will be taken. Commercial parts will be used when possible. No drive laser or wavequide The usual temptation is to use a waveguide will be used. inside the undulator at wavelengths of 100 µm or greater in order to minimize diffraction. This design also uses energy recovery of the beam without complete recirculation 2 180°. and bending arcs of х The FEL can be superconducting, but at 4K versus the more complicated and expensive 2K operation. This design also calls for low beam energy and good mode quality to ensure the beam is useable for laboratory purposes [19].

The absence of a waveguide will result in a limit to the length of the undulator. Diffraction in a long undulator, without scraping, would require too large a gap between the magnets. A large gap reduces the magnetic field in the undulator, thus reducing gain. Diffraction of the long wavelength optical beams may cause the optical

beam to scrape the undulator and be absorbed, or clip the optical mode wings. This presents a conflict in determining undulator length: For larger gain, a longer undulator is desirable (because $gain \propto N^3$), but at longer wavelengths diffraction significantly reduces qain. However, at lower electron beam energies, γ also decreases and since $gain \propto 1/\gamma^3$ it is possible to get respectable gain by keeping γ low, while using a shorter undulator. A ~ 100 period undulator is now common, but we consider 10 periods or less. In the case of longer wavelengths (~ 100 μ m), this appears to be the only option for successful operation without a waveguide.

A. DESIGN CHARACTERISTICS COMMON TO ALL WAVELENGTHS

The following design criteria are well established and will be held constant for all further designs discussed in this thesis:

$$I \sim 0.1 \text{ A}$$

 $\Delta t_b \sim 5 \text{ ps}$
 $q = 0.2 \text{ nC}$
 $f \sim 500 \text{ MHz}$
 $\lambda_0 \sim 3 \text{ cm}$
 $K \sim 1$
 $g \sim 1.2 \text{ cm}$

where I is the average electron beam current, Δt_b is the pulse length, q is the charge of each pulse, f is the frequency of electron pulses, λ_0 is the period of the undulator, K is the undulator parameter (which is

proportional to the strength of the magnetic field in the undulator), and g is the gap of the undulator.

1. ~ 10 Micron Wavelength Range Design

Beginning with the well-known equation for the massenergy relationship ($E_b = \gamma mc^2$) we get

$$\gamma = \frac{E_b}{mc^2}$$
 (VI.1)

where E_b is the electron beam energy, m is the electron mass, and c is the speed of light. Using Equation (VI.2), which describes the resonance condition for a relativistic electron beam, it is clear that as γ increases the wavelength of the optical beam will decrease, giving

$$\lambda = \frac{\lambda_0 (1 + K^2)}{2\gamma^2} \qquad (VI.2)$$

Now, if K is a constant of ~ 1, and λ_0 is also a constant of ~ 3 cm, and an optical wavelength λ of ~ 10 μ m is desired, then a beam energy of ~ 30 MeV is desired.

In this wavelength regime, optical radiation at ~ 10 μ m propagates easily through the atmosphere and optics are easy to find due to the many types of lasers already in operation. Conveniently, a standard undulator (of ~100 periods) can be used with satisfactory optical beam performance, due to the low level of diffraction present. During the course of this research, it became apparent that many of the issues for this wavelength range can be solved relatively easily with off-the-shelf products, and

therefore this thesis will not investigate further into design solutions for this wavelength.

2. ~ 30 Micron Wavelength Range Design

Using the same analysis as in Section 1, but using a wavelength λ of ~ 30 μ m, a calculated beam energy of roughly ~ 20 MeV is required. Like the ~ 10 μ m range previously, this part of the THz frequency spectrum is less challenging from a design standpoint because the diffraction is not large enough to require a non-standard length undulator. Beam clipping or scraping (the loss of power from the optical beam due to impingement on the undulator ends) is not serious.

3. ~ 100 Micron Wavelength Range Design

Again, following the above process to determine the beam energy required for operation, using a λ of ~ 100 μ m, a calculated beam energy of ~ 10 MeV is desired. At this wavelength, clipping of the beam begins to become а limiting factor on operation, while using a standard length The useful transmission distance through the undulator. atmosphere starts to severely limit the applications for such a beam. To minimize the optical power lost, shorter undulator designs and the effects of beam clipping and scraping become more serious and will need to be considered.

4. ~ 300 Micron Wavelength Range Design

Using the same process as in the previous three cases, the beam energy required for operation, using a λ of ~ 300 μ m, is determined to be ~ 5 MeV. Taking into account diffraction, this design will require serious consideration of undulator length and the effects of clipping/scraping. With a standard-length undulator, the optical beam would be so severely clipped that it would fail to operate. It has been shown, however, that respectable gain can still occur in as few as six undulator periods, while the shortened undulator design minimizes beam clipping. Chapter VII will investigate further the effects of clipping on beam power and in consideration of undulator design.

As with the ~ 100 μ m range radiation, the longer wavelengths of the ~ 300 μ m range radiation do not propagate long distances without losing much of the power density to diffraction and extinction in the atmosphere. This serves to limit the applications for a FEL at these frequencies. Additionally, optics problems that are well understood for the shorter wavelengths are not easily solved in this range. This makes this design problem significantly more demanding.

B. TABLE OF PARAMETERS

λ (μm)	γ	E (MeV)
~ 10	~ 59	~ 30
~ 30	~ 39	~ 20
~ 100	~ 20	~ 10
~ 300	~ 10	~ 5

A compilation of the above designs is displayed in Table 3.

Table 3. Desired energies to attain wavelengths of interest.

It is clear that for FEL designs at wavelengths of 100 μ m or longer, there will have to be a compromise between beam clipping and a shortened undulator. The following chapter investigates further the effect of clipping through the use of computer simulations.

VII. CLIPPING SIMULATION RESULTS

This chapter does not simulate the designs discussed in the previous chapter. In order to do that, a 4D code is needed and is now being developed. This chapter takes advantage of the NPS 3D Oscillator FEL Code that is available now. The current 3D code uses the Lorentz force equations and the parabolic wave equation to simulate the motion of the electrons they pass through as an The code follows the electron path electromagnetic field. in the optical cavity and includes known losses, as well as allowing the required number of undulator passes to reach steady state [20].

Beam clipping/scraping is the complete removal of the optical beam that intersects an absorbing material placed in the beam pipe. This occurs due to the diffraction of the optical beam, which increases with wavelength. For this simulation, the optical beam is removed on contact with the circular absorber placed at the ends of the undulator resulting in an additional loss in the resonator system.

The 3D code was altered to include this effect in order to determine the affects on the performance of the FEL. There are four clips per pass: the first occurs as the optical beam exits the undulator, the second when it re-enters the undulator after reflecting off of the partially transmitting mirror, the third when it exits the opposite end of the undulator, and the fourth when it returns into the undulator after reflecting off of the fully reflecting mirror. Due to the increased diffraction caused by each clip, each successive clip enhances the clipping at the next location. The radius of the circular absorber is determined by specifying the fractional power dP/P that would be removed from the fundamental mode passing through the end of the undulator. The fraction of the theoretical fundamental mode clipped is symbolized as dP/P. The effect of clipping was studied for both strong and weak optical fields.

Dimensionless parameters were selected in the 3D code leading to a gain of approximately 80%, and a Q value giving 5% loss per pass, a mirror separation distance of ten times the undulator length, and twenty undulator periods, and a Rayleigh length that is one third of the undulator length.

A. WEAK FIELD GAIN

The NPS 3D FEL Oscillator code is used to determine weak field gain to evaluate the startup mechanism. In weak optical fields, where the dimensionless optical field is $|a_0| < \pi$, the system has not reached saturation and extraction η is small. Weak field gain, which is defined as the fractional increase in optical power/pass, is of interest to determine whether the FEL will start from spontaneous emission; weak field gain/pass must exceed the round trip loss/pass now including the clipping loss. The weak-field gain of a FEL is determined by running the 3D codes over many passes until gain/pass is constant [21].

The 3D code outputs reported here determine the effect of beam clipping, including the initial phase velocity of the electrons v_0 , gain G, extraction η , and optical mode

shape. These simulations assume a long pulse and do not model a particular FEL; they are used to study the effects of clipping and cannot simulate all actual effects. Figures 14 and 15 indicate the results of these simulations for weak fields.



Figure 14. Weak optical field gain vs. optical beam clipping.

The optical mode shape of the beam was inlaid on the graph of gain G versus clipping percentage dP/P for weak fields at four different clipping percentages in order to illustrate how clipping effects the mode shape. The optical mode to the far left occurs when there is no clipping/scraping and is very close to the theoretical fundamental Gaussian mode defined by the resonator cavity. As the amount of clipping is increased, the optical mode shape becomes more pointed (or focused around the electron beam) and finally develops a slight "shoulder" as seen in the far right optical mode. As the clipping parameter dP/P is increased from 1% to 10%, the optical mode shape increasingly departs from the original fundamental mode and is composed of a few higher order modes. At greater than 10% clipping there is sufficient loss so that ~ 80% gain is not enough to sustain the FEL.



Figure 15. Optimal electron phase velocity v_0 vs. optical beam clipping for weak fields.

Once the clipping starts, the optimal v_0 shown in Figure 15 quickly levels off and remains relatively constant. Clipping appears to have little affect on the optimal electron phase velocity v_0 .

B. STRONG FIELD EXTRACTION

In strong fields, the FEL reaches saturation quickly over a few hundred passes and the extraction η becomes constant in steady-state. Figures 16 and 17 indicate the results of strong optical fields at steady-state saturation.



Figure 16. Strong optical field extraction η vs. optical beam clipping.

The optical mode shape of the beam is inlaid on the graph of extraction versus clipping for strong fields. The five examples illustrate how clipping affects the mode shape. As the optical mode shapes are viewed from left to right some interesting changes occur. A large departure from the fundamental mode is prevalent at dP/P = 0%, but quickly disappears with only a small amount of clipping.

This indicates that a very small amount of clipping can quickly eliminate these secondary modes. At dP/P = 0.1%, the resulting optical mode shape most closely matches the Gaussian fundamental mode shape. As dP/P increases from 0.1% to 9%, the optical mode shapes behave similarly to that in weak fields: it becomes more pointed and develops a shoulder. During this progression, the simulation is picking combinations of modes to maximize power, something that occurs naturally in the FEL. One conclusion is that a small amount of clipping does a lot to keep the optical mode shape in the fundamental mode.



Figure 17. Optimal electron phase velocity v_0 vs. optical beam clipping for strong fields.

Figure 17 plots the optimum value of the electron phase velocity v_0 versus dP/P. In the case of strong

fields, an interesting result occurs at dP/P = 0%. The optimal v_0 jumps significantly to large values. This may not be what an experiment would experience because this simulation does not take into account all of the real effects that impact operation, such as the finite optical pulse length and slippage. After the initial jump in the optimal v_0 , the value of v_0 quickly levels and remains relatively constant as dP/P increases to 9%.

For each figure, the FEL stops operating at a dP/P of ~ 10%. It is clear that the dP/P parameter cannot be simply viewed as an additional loss in the FEL resonator. First of all, when the clipping absorber is encountered and the outer wings of the mode are removed, diffraction to an even larger mode area will occur when propagating to and from both mirrors and along the undulator. So, one encounter with clipping dP/P ~ 10% results in clipping more than 10% at subsequent encounters. Secondly, the clipping absorber is encountered four times each pass. So, actual steady-state clipping of ~ 20%/encounter may explain the saturation observed.

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VIII. CONCLUSION

There have been many improvements to Free Electron Laser operation since John Madey proposed the original FEL in 1970. There are many considerations in the design of a new high-energy laser system, and this thesis has begun to address the area of optical component design and the effects of undulator clipping/scraping for an FEL operating in the 1-30 THz regime.

Some materials are found that can successfully operate in the THz regime at power levels ranging from milliwatts to kilowatts. Until now, there has been only limited research in optical properties in the THz regime at the suggested in this thesis. higher powers Absorption coefficients and transmittances are needed for the entire THz spectrum considered here. Many materials were considered, but many other materials were not considered due to lack of available data. To continue this research essential that accurate complete it is and data be available, and this is a suggested area of continued research.

FEL simulation codes will Existing provide many answers to the design requirements for any future FEL. The clipping effects considered in the simulation section of this thesis suggest potentially beneficial changes that could be incorporated into future FELs. It is important to verify these results by the NPS 4D FEL oscillator code now The results of optical under development. the beam clipping/scraping simulation indicate that there may be a positive effect from a small amount of beam clipping on the

beam piping at the exits of the undulator, illustrated by the reduced number of optical modes present in the optical beam following a small amount of beam clipping.
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